

1. General description

Planar passivated sensitive gate Silicon Controlled Rectifier in a SOT54 (T0-92) plastic package.

2. Features and benefits

- High voltage capability
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate

3. Applications

- Ignition circuits
- Lighting ballasts
- Protection circuits
- Switched Mode Power Supplies

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage			-	-	600	V
V _{RRM}	repetitive peak reverse voltage			-	-	600	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>		-	-	8	A
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>		-	-	0.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	-	0.8	A
Static chara	acteristics		1				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>		-	50	200	mA





5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	А	anode		а -Ң к
2	G	gate		Ġ sym037
3	К	cathode	TO-92 (SOT54)	
			10-92 (50154)	

6. Ordering information

Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
BT169G	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54
BT169G/DG	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54

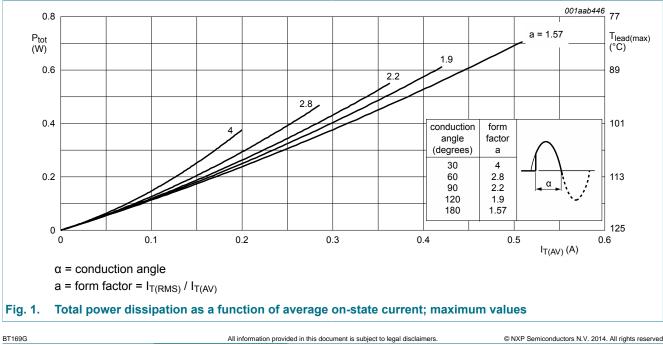
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Limiting values 7.

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

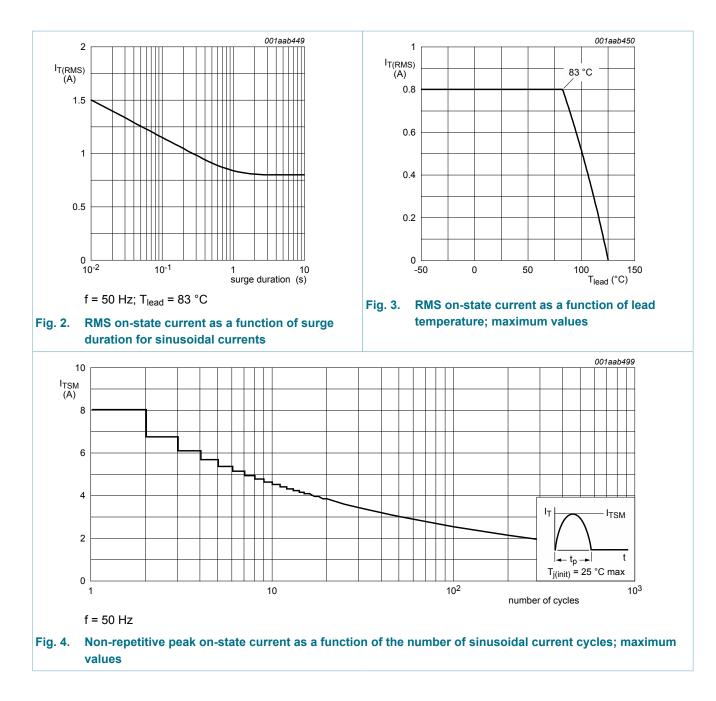
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
V _{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; $T_{lead} \le 83 \text{ °C}$; Fig. 1	-	0.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; $T_{lead} \le 83 \text{ °C}$; Fig. 2; Fig. 3	-	0.8	A
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 10 \text{ ms}; \text{ Fig. 4}; \text{ Fig. 5}$	-	8	A
		half sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 8.3 \text{ ms}$	-	9	A
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.32	A ² s
dI _T /dt	rate of rise of on-state current	$I_T = 2 \text{ A}; I_G = 10 \text{ mA}; \text{dI}_G/\text{dt} = 100 \text{ mA}/$ µs	-	50	A/µs
I _{GM}	peak gate current		-	1	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



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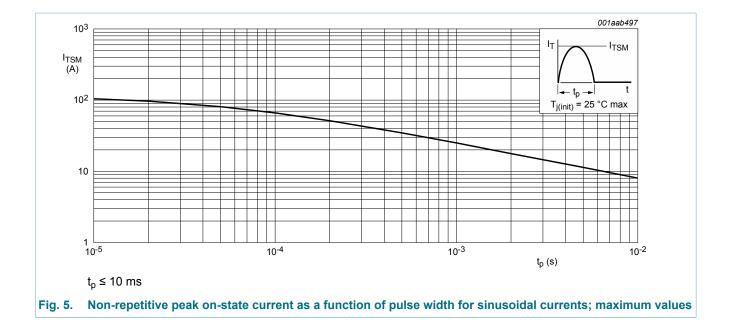
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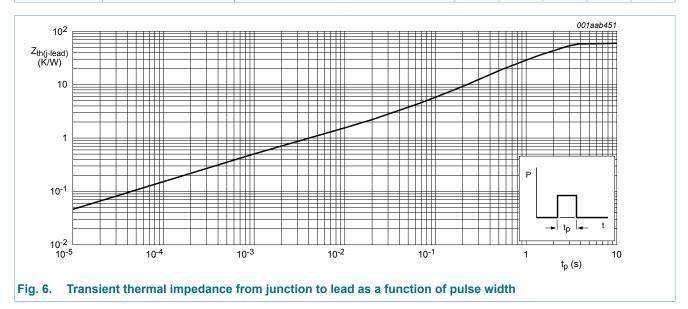
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8. Thermal characteristics

Table 5. T	hermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	Fig. 6	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W

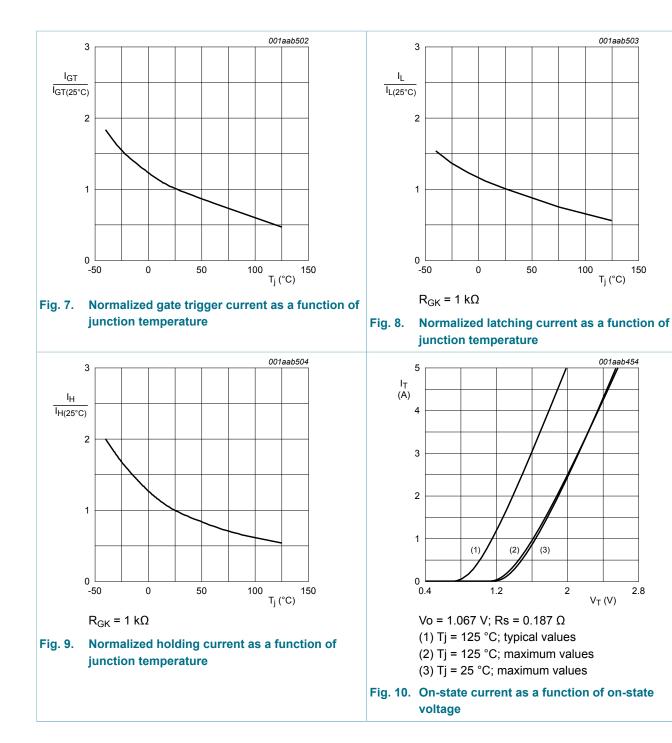


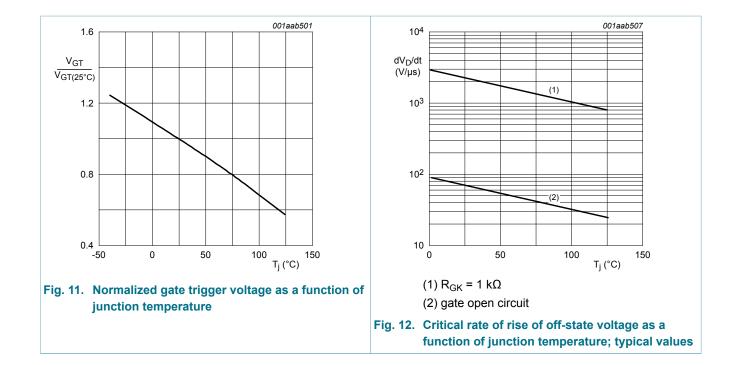
9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics		l l			
I _{GT}	gate trigger current	V_D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 7	-	50	200	mA
IL	latching current	$V_D = 12 \text{ V}; \text{ I}_G = 0.5 \text{ mA}; \text{ T}_j = 25 \text{ °C};$ Fig. 8	-	2	6	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	2	5	mA
V _T	on-state voltage	I _T = 1.2 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; Fig. 11	-	0.5	0.8	V
		V _D = 600 V; I _T = 10 mA; T _j = 125 °C; Fig. 11	0.2	0.3	-	V
I _D	off-state current	V_D = 600 V; T _j = 125 °C; R _{GK} = 1 k Ω	-	0.05	0.1	mA
I _R	reverse current	V_{R} = 600 V; T _j = 125 °C; R _{GK} = 1 k Ω	-	0.05	0.1	mA
Dynamic cl	haracteristics	I I	I			
	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 12	500	800	-	V/µs
		V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	-	25	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 2 A; V _D = 600 V; I _G = 10 mA; dI _G / dt = 0.1 A/µs; T _j = 25 °C	-	2	-	μs
t _q	commutated turn-off time	$\begin{split} &V_{DM} = 402 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; \text{I}_{TM} = 1.6 \text{ A}; \\ &V_{R} = 35 \text{ V}; (\text{dI}_{\text{T}}/\text{dt})_{\text{M}} = 30 \text{A}/\text{\mu}\text{s}; \text{dV}_{\text{D}}/\\ &\text{dt} = 2 \text{V}/\text{\mu}\text{s}; \text{R}_{\text{GK}} = 1 \text{k}\Omega; (\text{V}_{\text{DM}} = 67\% \text{of} \\ &V_{\text{DRM}}) \end{split}$	-	100	-	μs

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10. Package outline

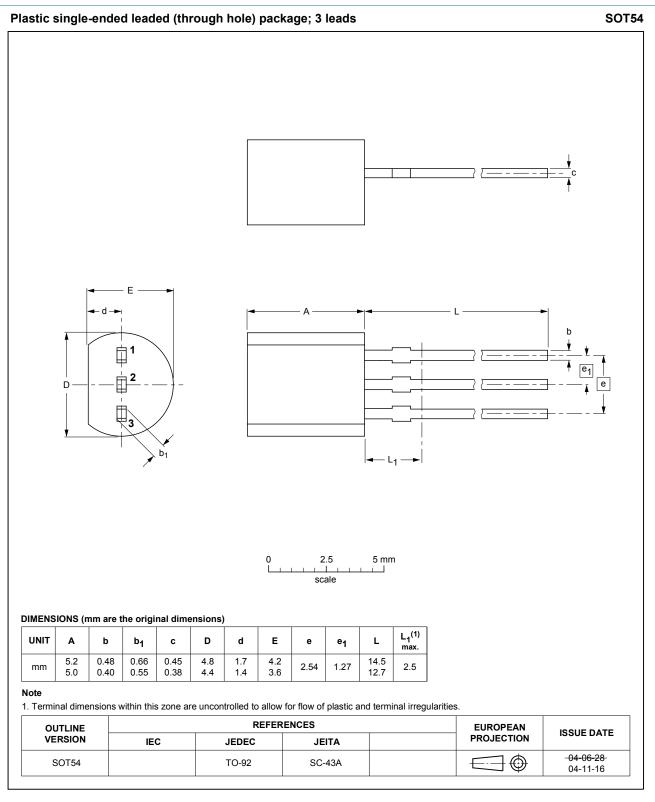


Fig. 13. Package outline TO-92 (SOT54)

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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[2] The term 'short data sheet' is explained in section "Definitions".

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